

View Online at <https://aerobasegroup.com/nsn/5961-01-424-6319>

Inclosure Material:

Metal

Overall Length:

0.115 inches

Overall Height:

0.092 inches

Overall Width:

0.062 inches

Function For Which Designed:

Phototransistor

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter to collector, base open

Power Rating Per Characteristic:

50.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 1 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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